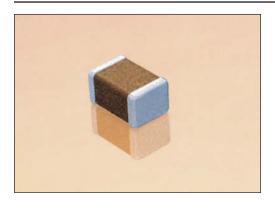
### **X5R Dielectric**



### **General Specifications**

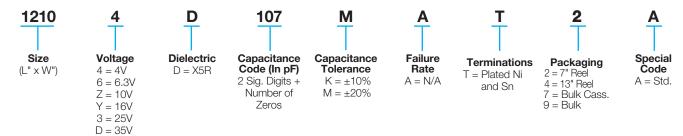


5 = 50V

#### **GENERAL DESCRIPTION**

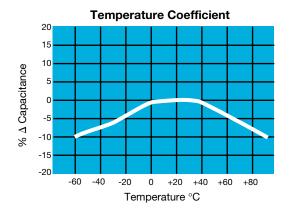
- General Purpose Dielectric for Ceramic Capacitors
- EIA Class II Dielectric
- Temperature variation of capacitance is within ±15% from -55°C to +85°C
- Well suited for decoupling and filtering applications
- Available in High Capacitance values (up to 100μF)

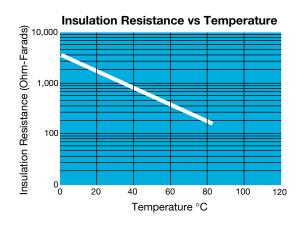
#### PART NUMBER (see page 2 for complete part number explanation)



NOTE: Contact factory for availability of Tolerance Options for Specific Part Numbers. Contact factory for non-specified capacitance values.

#### TYPICAL ELECTRICAL CHARACTERISTICS





# **X5R Dielectric**



## **Specifications and Test Methods**

Parame	ter/Test	X5R Specification Limits	Measuring Conditions									
Operating Tem		-55°C to +85°C	Temperature Cycle Chamber									
Capac	itance	Within specified tolerance										
		≤ 2.5% for ≥ 50V DC rating	Freq.: 1.0 kHz ± 10%									
Dissipation	on Factor	≤ 3.0% for 25V DC rating	Voltage: 1.0									
		≤ 3.5% for 16V DC rating	For Cap $> 10 \mu F$ ,	0.5Vrms @ 120Hz								
		≤ 5.0% for ≤ 10V DC rating	01 1 1									
Insulation I	Resistance	100,000MΩ or 500MΩ - μF,	Charge device with									
		whichever is less	120 ± 5 secs @ ro									
Dielectric	Strength	No breakdown or visual defects	Charge device with 300 1-5 seconds, w/charge limited to 50	and discharge current 0 mA (max)								
	Appearance	No defects	Deflection									
	Capacitance	≤ ±12%	Test Time: 3	30 seconds								
Resistance to	Variation	2 2 12 / 0	1mm/sec									
Flexure	Dissipation	Meets Initial Values (As Above)										
Stresses	Factor	TVIOUS IT ITEM VALAGE (1671,0000)										
	Insulation	≥ Initial Value x 0.3	90 1	mm								
	Resistance	≥ 95% of each terminal should be covered	Dip device in eutection									
Solder	rability	≥ 95% of each terminal should be covered with fresh solder	for 5.0 ± 0.									
	Appearance	No defects, <25% leaching of either end terminal	101 3.0 ± 0.	3 SECONOS								
	Capacitance	•										
	Variation	≤ ±7.5%										
	Dissipation		Dip device in eutectic									
Resistance to	Factor	Meets Initial Values (As Above)	seconds. Store at room hours before measurin									
Solder Heat	Insulation	Mosta Initial Values (As Abova)	Hours before measurin	g electrical properties.								
	Resistance	Meets Initial Values (As Above)										
	Dielectric	Meets Initial Values (As Above)										
	Strength		01 1 5500 00	00 0 1 1								
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes								
	Capacitance Variation	≤ ±7.5%	Step 2: Room Temp	≤ 3 minutes								
	Dissipation											
Thermal	Factor	Meets Initial Values (As Above)	Step 3: +85°C ± 2°	30 ± 3 minutes								
Shock	Insulation	A4	O: 4 D T	0 1 1								
	Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes								
	Dielectric	Meets Initial Values (As Above)	Repeat for 5 cycles ar									
	Strength		24 ± 2 hours at room	temperature								
	Appearance	No visual defects	Charge device with 1.5X rated voltage in									
	Capacitance Variation	≤ ±12.5%	test chamber set at 85°C ± 2°C for 1000 hou									
	Dissipation		(+48, -0). Note: Contact									
Load Life	Factor	≤ Initial Value x 2.0 (See Above)	CV devices that are teste	ed at 1.5X rated voltage.								
2000 20	Insulation		D	and an analyst of the State								
	Resistance	≥ Initial Value x 0.3 (See Above)	Remove from test ch									
	Dielectric	NA t - 1-242-1 \ / - 1 \ \ / A - \ A   \ \	at room temperature for 24 ± 2 hours before measuring.									
	Strength	Meets Initial Values (As Above)	Delote III	casaring.								
	Appearance	No visual defects	Store in a test chamb	er set at 85°C + 2°C/								
	Capacitance	≤ ±12.5%	85% ± 5% relative hu									
	Variation		(+48, -0) with rate									
Load Humidity	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	, -, -, -	5 11								
Humble	Insulation	, ,	Remove from chamber and stabilize at									
	Resistance	≥ Initial Value x 0.3 (See Above)	room temperature and humidity for									
	Dielectric		$24 \pm 2$ hours before measuring.									
	Strength	Meets Initial Values (As Above)										
		1	<u> </u>									



## **X5R Dielectric**





#### PREFERRED SIZES ARE SHADED

																			ш																							
SIZ	E		0201		0402				0603							0805							1206						1210							1812						
Solder	rina	R	eflo	w Only R		Reflow Only			Reflow Only							Reflow/Wave						Reflow/Wave						Reflow/Wave							Reflow Only							
Packag		_		Pape		All Paper			All Paper							Paper/Embossed						Paper/Embossed						Paper/Embossed							All Embossed							
(L) Length	MM (in.)			± 0.0 ± 0.0			1.00 ± 0.10 (0.040 ± 0.004)				1.60 ± 0.15 (0.063 ± 0.006)							Г		2.01 ± 0.20 (0.079 ± 0.008)					3.20 ± 0.20 (0.126 ± 0.008)					3.20 ± 0.20 (0.126 ± 0.008)							4.50 ± 0.30 (0.177 ± 0.012)					
000 \0/6dtb	MM			± 0.0		⊢		0.50 :				0.81 ± 0.15							$\vdash$		.25 ±			_	1.60 ± 0.20								3.20 ±									
(W) Width	(in.)			± 0.0		┖	(0.020 ± 0.004) 0.25 ± 0.15				(0.032 ± 0.006) 0.35 ± 0.15							┖		)49 ±				$(0.063 \pm 0.008)$ $0.50 \pm 0.25$						(0.098 ± 0.008)							126 ±					
(t) Terminal	MM (in.)			± 0.0 ± 0.0			$0.25 \pm 0.15$ (0.010 ± 0.006)				(0.014 ± 0.006)									.50 ±					$0.50 \pm 0.25$ $(0.020 \pm 0.010)$					$0.50 \pm 0.25$ (0.020 ± 0.010)						0.61 ± 0.36 (0.024 ± 0.014)						
	WVDC			16		4		3 10 16 25 50									6.3					50	6.3					0								10						
Cap	100				А																																					
(pF)	150 220				A						С																															
	330	H			A	Н					С	$\vdash$							$\vdash$						$\vdash$	-	+	+	+						_					—		
	470				A						С																				اس	_	$\overline{}$		$\subseteq$	-W-	>					
	680	L			А						С	L													Ш			$\perp$	$\perp$	4	•	$\leq$	_	\	_	١)	T					
	1000			Α	Α						С																					_	. ]		_		_					
	1500 2200		Α	A							С																						بر									
	3300	$\vdash$	A	A		$\vdash$	$\vdash$	$\vdash$	$\vdash$	$\vdash$	С	Н						$\vdash$	$\vdash$			_			$\vdash$	$\dashv$	+	+	+				"1	:					$\dashv$	—		
	4700		A							С								G												Τ		1				I	ı					
	6800		А							С								G																								
Cap	0.010		Α							С								G																								
(µF)	0.015 0.022	Α							С	С						G	G	G						Ν																		
	0.022	A			-				С							G	G	G						N				+	+	+		+	+									
	0.033	Α							С							G	G	G						N																		
	0.068								С							G		G						Ν																		
	0.10	Α						С	С							G		G				Z		Ν																		
	0.15															G						N	N																			
	0.22	⊢	$\vdash$	$\vdash$	$\vdash$	⊢	С	-	$\vdash$	$\vdash$		⊢			G	G G		$\vdash$	$\vdash$			N	N	_	$\vdash$	$\dashv$	+	+	C	٧	+	+	+	+	+	$\vdash$	┢		$\dashv$	—		
	0.33					С	С								G	G						N						Q	Q							X						
	0.68														G							N																				
	1.0	Г				С	С	С					G	G	G	J					N	N		P*				Q	Q	Т				Х	Х	Х				_		
	1.5																			N	N	N.I.						_						7	\ \/					7		
	2.2	H	$\vdash$	$\vdash$	+	С		1	$\vdash$	-		G	G	J	J			-	N	N	N	Ν			$\vdash$		-	Q	+	+	+	+	+	Z	X		$\vdash$	$\vdash$		Ζ		
	3.3 4.7											G	G						N	N N	N	N*						Q Q					Z	Z								
	10											K							N	N	N				Q			Q				Z										
	22																		N						Q	Q	Q			T	Z		: Z	Z*								
	47					1					1	l													Q						Z						1					
	100 WVDC	6.3	3 10	16	25	4	6.3	10	16	25	50	4	6.3	10	16	25	35	50	6.3	10	16	25	35	50	6.3	10	16 3	25 :	35 5	0	Z Z <sup>4</sup>		) 16	3 25	35	50	6.3	10	25	50		
SIZ		J		201	1_0	Ė	, 5.0		02	1-0	,50	Ė	4 6.3 10 16 25 35 50 <b>0603</b>						1	0805					6.3 10 16 25 35 50 <b>1206</b>						10.0		12		, 50	, 55	6.3 10 25 50 <b>1812</b>					
Letter	Α			E		C			J			K	M				N			Q			Х			Υ		7														
Max.	0.33			.71		0.0			0.94 (0.037)			1.02			.27	,		40		1.7			2.29			2.54	,	2.														
Thickness	(0.013)		(U.	028)		(0.0)	04)	(	U.UJ	11)	1 ((	0.040	J)	(U.	050	)	(U.U	055)		(0.07)	U)	1 (	(0.09)	(U)	1 (0	.100	)	(0.1)	10)	1												



\*Optional Specifications - Contact factory

NOTE: Contact factory for non-specified capacitance values